SEMI-CONDUCTOR LABORATORY: CAPABILITIES OVERVIEW

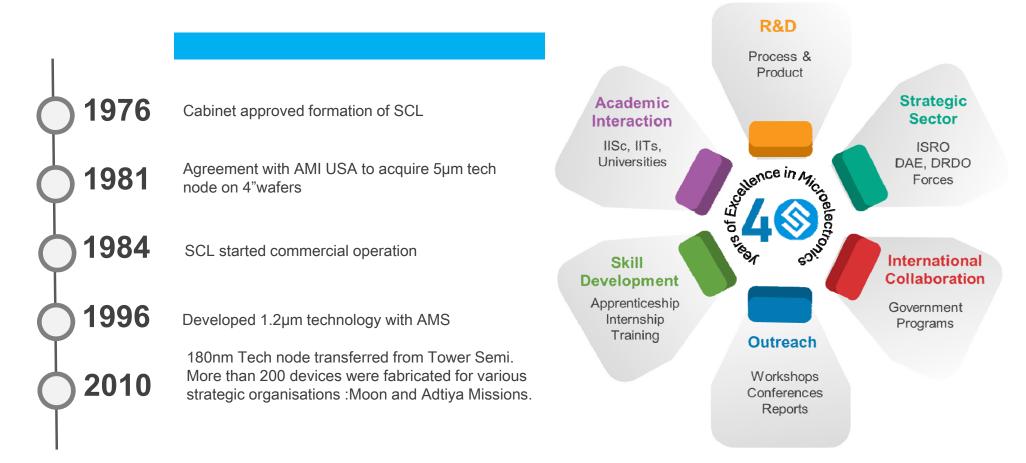
Kamaljeet Singh





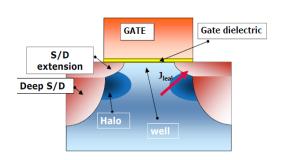
Brief History





Fab-lines

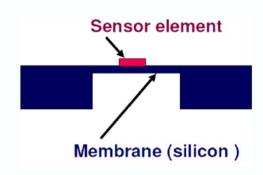




8" Wafer Fab-line with 180 nm CMOS technology for VLSI

- Digital, Analog and Mixed Signal
- Charge Coupled Devices
- RADHARD Capability Developed

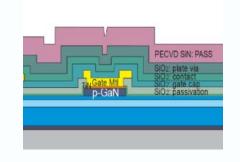
72 Equipment (Process & Metrology)



6" Wafer Fab-line dedicated to MEMS & Detectors Fabrication

- Silicon Technology
- Support for III-V devices

44 Equipment (Process & Metrology)



6" GaN on Si Technology:

- Epitaxial growth of III-V
- GaN on Si Power HEMT
- e-Mode device for 200V and 650V

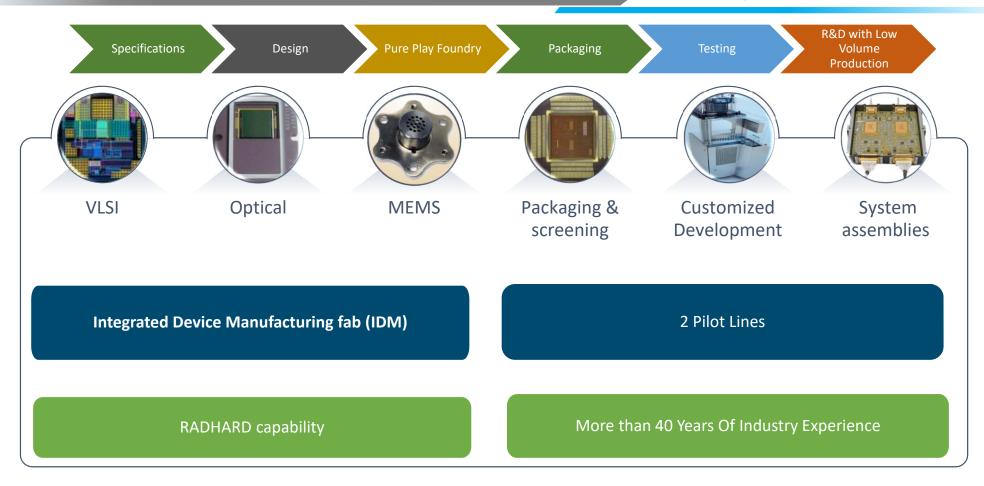
 15 Equipment
 (Process & Metrology)

SCL 180 nm CMOS fab is qualified as per JDEC JP001A guidelines



Integrated Device Manufacturer

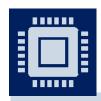






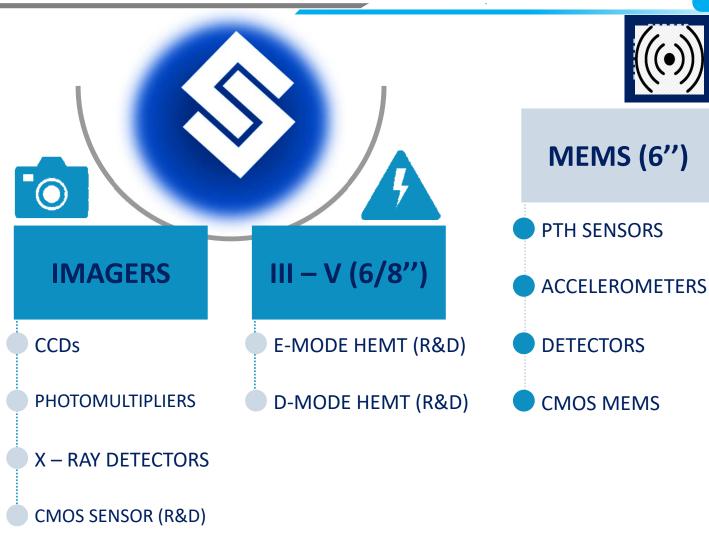
Product Portfolio





CMOS (8")

- ANALOG/DIGITAL/ MIXED SIGNAL
- RF CMOS
- LOGIC
- HIGH VOLTAGE (R&D)
- RAD HARD





Backend & Turnkey Solutions



Design Services

Design Enablement

Foundry Portfolio

Foundry Solutions

Backend Solutions

Turnkey Solutions

- Package Solution Development
- IC Test Program Development
- IC Testing- ATE, Semi-ATE, MEMS
- Material Testing
- Modelling of Process, Device & Systems
- Prototyping/ Shuttle
- Mask design
- System Development Kits (Education)







Analog

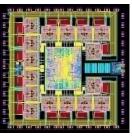
- **✓** ADC
- **√**LDO
- **✓** DAC
- ✓ C-to-D
- ✓ Programmable bias generator

Digital



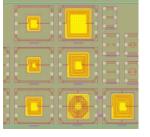
- ✓ Processor
- ✓ SPI
- ✓ CMOS Camera Configuration
- ✓ SADA ASIC
- ✓ CHC ASIC

Mixed Signal



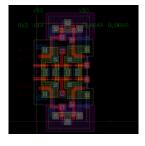
- ✓ Multi-core RDAS
- ✓ On-Board Controller
- ✓ Event Triggered
- ✓ DAS

RF



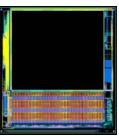
- ✓ Inductors
- ✓ VCO
- **✓** LNA
- ✓ Mixer

Memory



- ✓ 2 MBit, Synchronous SRAM
- ✓ 256K Bits, 32K X 8 Asynchronous SRAM
- ✓ DUAL PORT SRAM 4K x 8





- ✓ Read Out Integrated Circuit (ROIC)
- ✓ Frame Transfer CCD imager
- ✓ Visible CCD TDI Imager



Sensors & Photo Diode



Physical Sensors/Actuator Inertial Sensors Bio Medical Sensors

RF MEMS

Photo Detectors Chemical Sensors



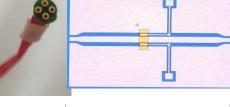
- ✓ Pressure Sensor
- ✓ Temperature sensors
- √ Humidity sensor
- ✓ Acoustic Sensors
- ✓ Micro-thruster
- ✓ Micro-valve



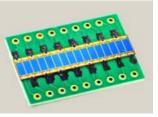
- ✓ Accelerometers
- √ Shock sensors
- √ G-switch
- √ Gyroscopes



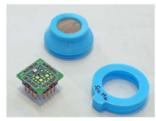
- √ Bio-Impedance Sensors
- ✓ Blood Cancer detectors
- ✓ Glucose Sensing



- ✓ RF Switch
- ✓ RF Antenna
- ✓ Varactor
- ✓ RF Filter



- ✓ Particle detectors
- ✓ Photo diode



- √ Gas Sensor
- ✓ Cantilever based gas sensing



Moore & More...

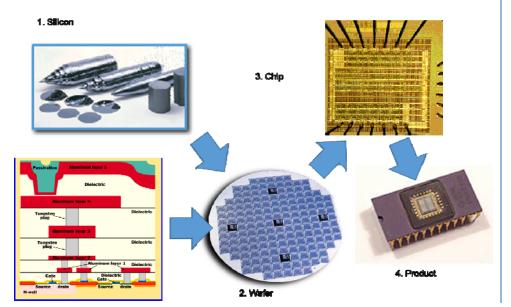


Approaches at SCL

Method 1 (Integration on a chip)



☐ Silicon On Chip (SOC)



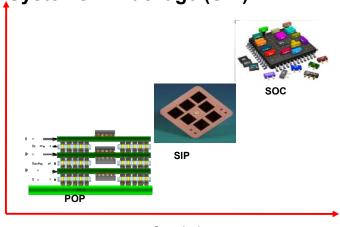
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Method 2: Packaging (Technology independent)

Packaging Solutions @SCL

Lead Time

- 3D packaging
- Package on Package (PoP)
- Multi Chip Modules (MCM) (TRL9)
- Systems in Package (SiP)



Complexity

Packaging



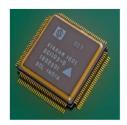
Ceramic













Metal









COB









सेमी - कंडक्टर लेबोरेटरी

EMI-CONDUCTOR LABORATORI





Varied sizes & technology nodes MULTICHIP MODULE

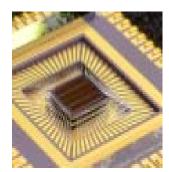
Multiple Power supply voltages 3D PACKAGING







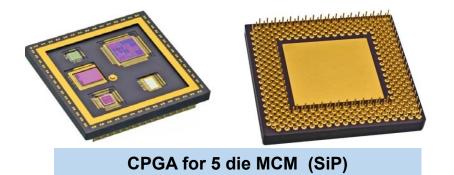
Package on Package

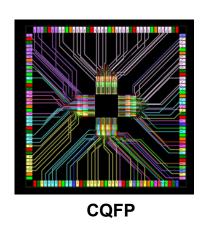


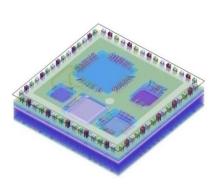
Die Stacking in ceramic package







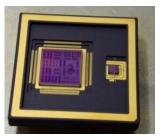




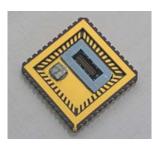
MCM Package simulation (SI and PI Simulations)



COB (109mm long die, 400 wire bonds on short ends)



2Die MCM (16 layer 181 CPGA ,370 wire bonds)



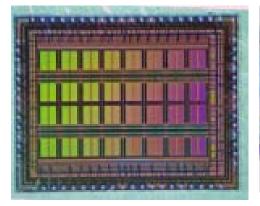
Accelerometer

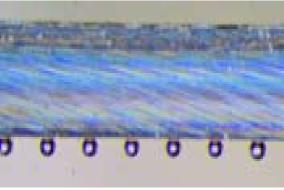


Plastic Packaging



- CMOS Devices in Plastic Package
- Reduction in size & weight
- Flexibility of varied pin count
- Cost effective



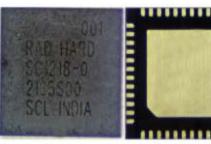


Die after bumping



PQFN64 (9mm x 9mm)





ADC-CQFP 64 to PQFN 48 (6mm x 6mm)





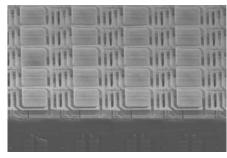
ASIC in PBGA168



CMOS-MEMS INTEGRATION

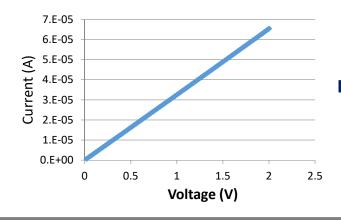


Integration of CMOS-MEMS wafers using CMOS-compatible process

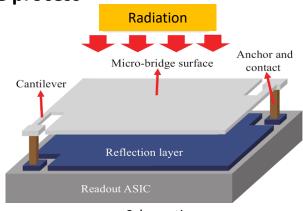


SEM Image of Released Structure

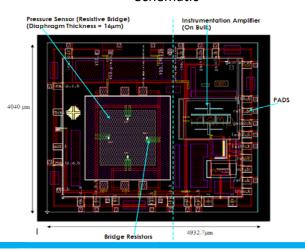
- 640x480 array
- Top Layer: Thin film
- Hanging structure



Integrated Pressure sensor

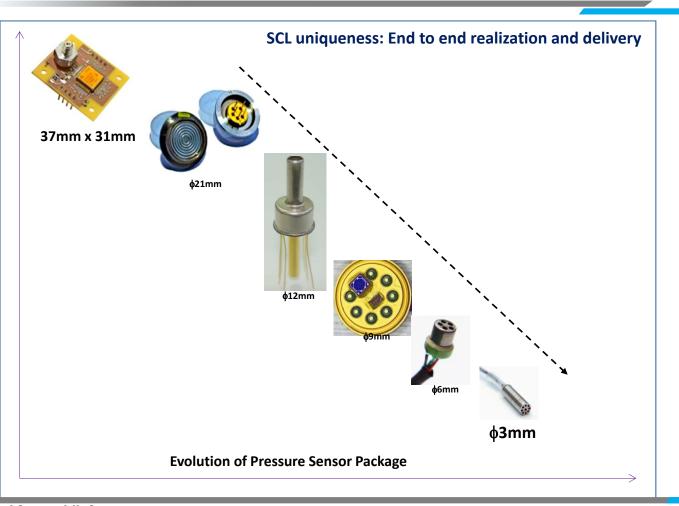


Schematic













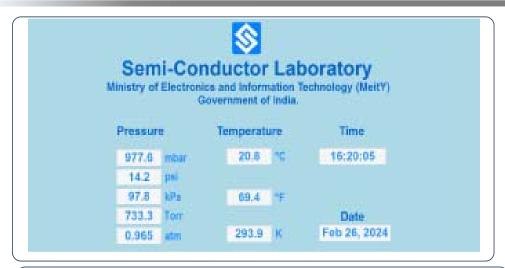
MAP/TMAP Sensor



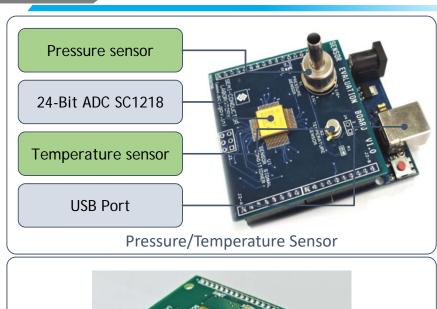
Diabetic foot mapping















Customized Products



Combination of various processes/technologies

Customization as per the requirements

Vacuum packaging to achieve Q-factor (~1000)

Miniaturized application board

Heater on flexible substrate

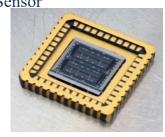
Combination of sensors



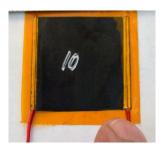


Thermal Flow Sensor

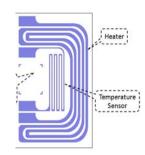




Gyro





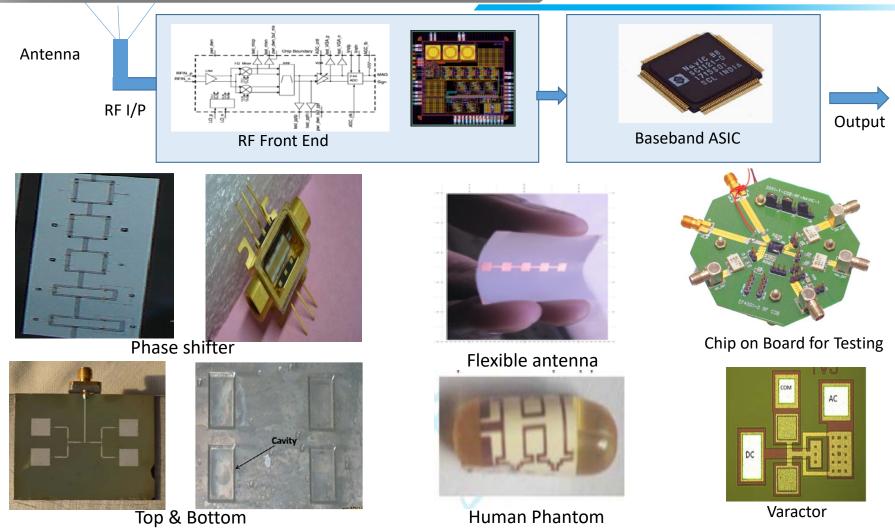


Heater & sensor



RFIC & RF Devices







PRODUCTS FOR MEDICAL TECHNOLOGY (MedTech)

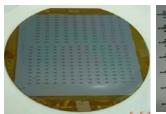


Device	Sensor Image	Collaboration	Brief Specifications	Remarks
Capacitive Sensor for detection of Cancer in White Blood Cell (WBC)		Academia	Nominal capacitance is of 5 pF at 20 KHz of frequency which reduces to 4.2 pF at 5000 KHz	 Detects the malignancy in Leukocytes of Human blood sample. Provides a quick time saving measurement with early detection of cancer compared to conventional clinical detection.
Bio Impedance Sensor for Catheter		Hospital	Impedance range : 1 – 10,000 $k\Omega$ with frequency sweep up to 100 kHz.	Measures electrical Impedance of mucosa cells of esophagus, for detection of GERD (Gastro- Esophageal Reflux Diseases)
Pulse Oximeter	S S S S S S S S S S S S S S S S S S S	DOE	Oxygen Saturation (SaO ₂): 0-100% Pulse Rate (BPM):: 30-240 bpm	Tend Data Storage Capacity up to 100 Patients / 24Hrs Runtime



Concept to Implementation

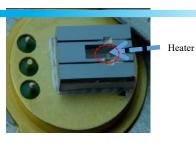




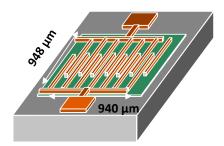








Interdigital Capacitor

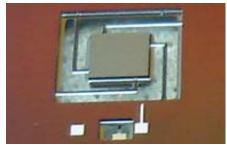


Si Chamber with embedded heater





Liquid level sensing









Accelerometer

Particle monitoring



International Collaboration



Multiplexed Analog Signal Processor - MANAS ALICE Experiment - CERN, Geneva (2007)



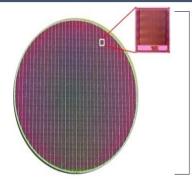
- Front End- SINP, Kolkata
- Backend Design in SCL
- 1.2 μm N-well CMOS Technology

Large scale production of a mixed signal ASIC

Total qty: 1,10,000

- 88,000 for Dimuon Spectrometer
- 88,000 for Photon Detector

Radiation Hardened LDOs RH - Low Dropout Voltage Regulators



- 1.2V and 1.8V Output
- 1.6A Full load
- 3.3V Supply



Chip-on-Board

- Device 1 1.2V/1.6A
- Device 2 1.8V/1.6A

Delivered a total of 30,000 dies to GSI, Germany

Summarization



- Unique IDM with CMOS & MEMS foundry
- R&D with emphasis on reliability
- In-house packaging, testing & quality assurance facility
- Quality products for niche sectors & international institutions
- Flexibility in process design
- Design expertise of varied domain
- Complete turnkey solution provider

